

Taiwan Semiconductor

200mA, 120 - 250V High Voltage SMD Switching Diode

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

- Case: SOD-323F
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 4.50mg (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I _F	200	mA	
V _{RRM}	120 - 250	V	
I _{FSM}	2.5	А	
V_F at I_F = 200mA	1.25	V	
T _{J MAX}	150	°C	
Package	SOD-323F		
Configuration	Single die		









ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
PARAMETER		SYMBOL	BAV19WS	BAV20WS	BAV21WS	UNIT
Marking code on the device			S5	S6	S7	
Power dissipation		PD	200			mW
Average forward current		I _F	200			mA
Repetitive peak reverse voltage		V _{RRM}	120	200	250	V
Pulse Width = 1s , Peak forward surge Square Wave				0.5		Α
current	Pulse Width = 1µs , Square Wave	IFSM	2.5		^	
Junction temperature range		TJ	-65 to +150			°C
Storage temperature range		T _{STG}	-65 to +150			°C



Taiwan Semiconductor

PARAMETER		CONDITIONS	SYMBOL	MIN	MAX	UNIT
Forward voltage ⁽¹⁾		I _F = 100mA, T _J = 25°C		-	1.00	V
		$I_F = 200 \text{mA}, T_J = 25^{\circ}\text{C}$	V _F	-	1.25	V
Reverse voltage	BAV19WS	I _R = 100μA, T _J = 25°C		120	-	V
	BAV20WS		V _R	200	-	V
	BAV21WS			250	-	V
Reverse current ⁽²⁾	BAV19WS	$V_{R} = 100V T_{J} = 25^{\circ}C$	I _R	-	0.1	μA
	BAV20WS	$V_{R} = 150V T_{J} = 25^{\circ}C$		-	0.1	μA
	BAV21WS	$V_{R} = 200V T_{J} = 25^{\circ}C$		-	0.1	μA
Junction capacitance		1MHz, $V_R = 0V$	CJ	-	5	pF
Reverse recovery time		$I_F = I_R = 30 \text{mA},$ $R_L = 100\Omega, I_{rr} = 3 \text{mA}$	t _{rr}	-	50	ns

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

RDERING INFORMATION			
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING	
BAVxWS RR	SOD-323F	3K / 7" Reel	
BAVxWS RRG	SOD-323F	3K / 7" Reel	
BAVxWS R9	SOD-323F	10K / 13" Reel	
BAVxWS R9G	SOD-323F	10K / 13" Reel	

Notes:

1. "x" is device code from "19"(BAV19WS) to "21"(BAV21WS)

2. "G" means green compound (halogen-free)



Taiwan Semiconductor

CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

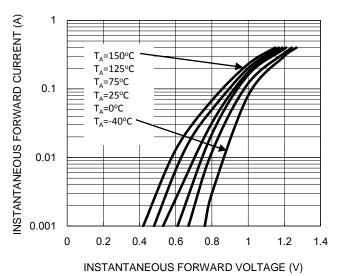


Fig.1 Typical Forward Characteristics

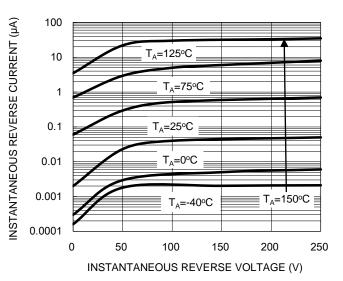


Fig.2 Typical Reverse Characteristics

Fig.3 Typical Capacitance VS. Reverse Voltage

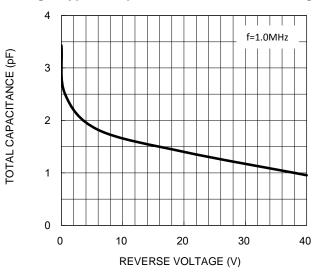


Fig.4 Power Derating Curve 250 200 POWER DISSIPATION (mW) 150 100 50 0 0 25 50 75 100 125 150 AMBIENT TEMPERATURE (°C)

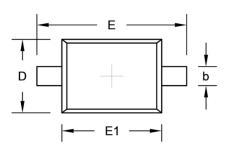


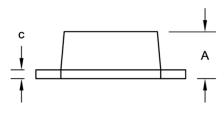
BAV19WS/BAV20WS/BAV21WS

Taiwan Semiconductor

PACKAGE OUTLINE DIMENSION

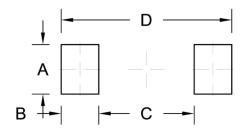
SOD-323F





DIM.	Unit (mm)		Unit (inch)		
	Min.	Max.	Min.	Max.	
A	0.60	1.00	0.024	0.039	
b	0.25	0.40	0.010	0.016	
с	0.05	0.25	0.002	0.010	
D	1.15	1.35	0.045	0.053	
E	2.30	2.80	0.091	0.110	
E1	1.60	1.80	0.063	0.071	

SUGGEST PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
А	0.83	0.033
В	0.63	0.025
С	1.60	0.063
D	2.86	0.113



BAV19WS/BAV20WS/BAV21WS

Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below :

 RD0306T-H
 BAV17-TR
 BAV19-TR
 IN3611
 NTE156A
 NTE525
 NTE571
 NTE5804
 NTE5806
 NTE6244
 ISS181-TP

 ISS193,LF
 ISS400CST2RA
 SDAA13
 SHN2D02FUTW1T1G
 LS4151GS08
 IN4449
 IN456A
 IN4934-E3/73
 IN914B
 IN914BTR

 RFUH20TB3S
 BAS 28
 E6327
 BAV199-TP
 BAW56DWQ-7-F
 BAW75-TAP
 MM230L-CAA
 IDW40E65D1
 JAN1N3600
 LL4151-GS18

 053684A
 SMMSD4148T3G
 707803H
 NSVDAN222T1G
 SP000010217
 ACDSW4448-HF
 CDSZC01100-HF
 BAV199E6433HTMA1

 BAV70M3T5G
 SMBT2001T1G
 NTE5801
 NTE5808
 NTE6240
 NTE6248
 DLM10C-AT1
 BAS28-7
 BAW56HDW-13
 BAS28

 TR
 TR
 IN
 IN
 IN
 IN
 IN
 IN
 IN
 IN
 IS
 IN
 IS
 IN
 IS
 IS
 IN
 I